3.3V ECL 2:1 Multiplexer

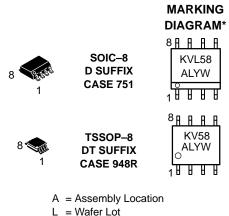
The MC100LVEL58 is a 2:1 multiplexer. The device is pin and functionally equivalent to the EL58 and works from a 3.3 V supply. With AC performance similar to the EL58 device, the LVEL58 is ideal for low voltage applications which require the ultimate in AC performance.

- 440 ps Typical Propagation Delays
- ESD Protection: >4 KV HBM, >200 V MM
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range: V_{CC} = 3.0 V to 3.8 V with V_{EE} = 0 V
- NECL Mode Operating Range: $V_{CC}=0$ V with $V_{EE}=-3.0$ V to -3.8 V
- Internal Input Pulldown Resistors
- Q Output will Default LOW with Inputs Open or at V_{EE}
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL–94 code V–0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 93 devices



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Y = Year

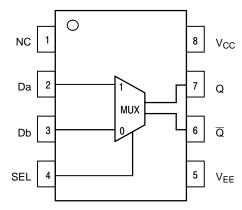
W = Work Week

*For additional information, see Application Note AND8002/D

ORDERING INFORMATION

Device	Package	Shipping
MC100LVEL58D	SOIC-8	98 Units / Rail
MC100LVEL58DR2	SOIC-8	2500 / Reel
MC100LVEL58DT	TSSOP-8	98 Units / Rail
MC100LVEL58DTR2	TSSOP-8	2500 / Reel

LOGIC DIAGRAM AND PINOUT: ASSIGNMENT



PIN DESCRIPTION

PIN	FUNCTION
Da, Db	ECL Data Inputs
Q, <u>Q</u>	ECL Differential Data Outputs
SEL	ECL Select Input
V _{CC}	Positive Supply
V _{EE}	Negative Supply
NC	No Connect

SEL	Data
H	a
L	b

MAXIMUM RATINGS (Note 1.)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		8 to 0	V
V_{EE}	NECL Mode Power Supply	$V_{CC} = 0 V$		8 to 0	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{l} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 to 0 6 to 0	V V
l _{out}	Output Current	Continuous Surge		50 100	mA mA
ТА	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to $44 \pm 5\%$	°C/W
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to $44 \pm 5\%$	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

1. Maximum Ratings are those values beyond which device damage may occur.

LVPECL DC CHARACTERISTICS V_{CC} = 3.3 V; V_{EE} = 0.0 V (Note 1)

			–40°C		25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	28		21	28		23	30	mA
V _{OH}	Output HIGH Voltage (Note 2.)	2215	2295	2420	2275	2345	2420	2275	2345	2420	mV
V _{OL}	Output LOW Voltage (Note 2.)	1470	1605	1745	1490	1595	1680	1490	1595	1680	mV
V _{IH}	Input HIGH Voltage	2135		2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage	1490		1825	1490		1825	1490		1825	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
IIL	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been establish circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.
 Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary ±0.3 V.
 Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

LVNECL DC CHARACTERISTICS V_{CC}= 0.0 V; V_{EE}= -3.3 V (Note 1.)

			–40°C		25°C						
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current		21	28		21	28		23	30	mA
V _{OH}	Output HIGH Voltage (Note 2.)	-1085	-1005	-880	-1025	-955	-880	-1025	-955	-880	mV
V _{OL}	Output LOW Voltage (Note 2.)	-1830	-1695	-1555	-1810	-1705	-1620	-1810	-1705	-1620	mV
V _{IH}	Input HIGH Voltage	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage	-1810		-1475	-1810		-1475	-1810		-1475	mV
I _{IH}	Input HIGH Current			150			150			150	μΑ
Ι _{ΙL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary \pm 0.3 V. 2. Outputs are terminated through a 50 ohm resistor to V_{CC}-2 volts.

AC CHARACTERISTICS V_{CC} = 3.3 V; V_{EE} = 0.0 V or V_{CC} = 0.0 V; V_{EE} = -3.3 V (Note 1.)

						25°C			85°C			
Symbol	I Characteristic			Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency			TBD			TBD			TBD		GHz
t _{PLH} t _{PHL}	Propagation Delay	D to Q SEL to Q	340 350	435 455	560 570	350 360	440 460	570 580	370 380	450 470	590 600	ps
t _{JITTER}	Cycle-to-Cycle Jitter			TBD			TBD			TBD		ps
t _r t _f	Output Rise/Fall Times Q (20% – 80%)		100		320	100		320	100		320	ps

1. V_{EE} can vary ± 0.3 V.

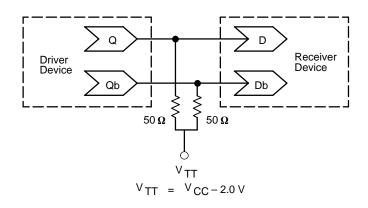


Figure 1. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020 – Termination of ECL Logic Devices.)

Resource Reference of Application Notes

AN1404	-	ECLinPS Circuit Performance at Non–Standard V_{IH} Levels
AN1405	_	ECL Clock Distribution Techniques
AN1406	_	Designing with PECL (ECL at +5.0 V)
AN1503	_	ECLinPS I/O SPICE Modeling Kit
AN1504	_	Metastability and the ECLinPS Family
AN1560	_	Low Voltage ECLinPS SPICE Modeling Kit
AN1568	_	Interfacing Between LVDS and ECL
AN1596	_	ECLinPS Lite Translator ELT Family SPICE I/O Model Kit
AN1650	_	Using Wire–OR Ties in ECLinPS Designs
AN1672	_	The ECL Translator Guide
AND8001	_	Odd Number Counters Design
AND8002	_	Marking and Date Codes
AND8020	_	Termination of ECL Logic Devices

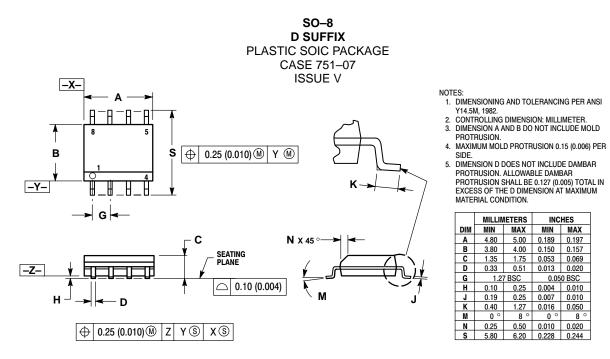
PACKAGE DIMENSIONS

4.00 0.150 0.157

 $\begin{array}{c|ccccc} 0.030 & BSC \\ \hline 0.25 & 0.004 & 0.010 \\ \hline 0.25 & 0.007 & 0.010 \\ \hline 1.27 & 0.016 & 0.050 \\ \hline 8 & 0 & 0 & 8 & 0 \\ \hline 8 & 0 & 0 & 8 & 0 \\ \hline 1 & 0 & 0 & 0 & 8 & 0 \\ \hline 1 & 0 & 0 & 0 & 0 & 0 \\ \hline$

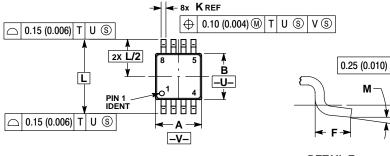
0.50 0.010 0.020

0.050 BSC

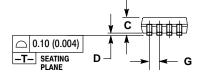


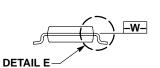
PACKAGE DIMENSIONS

TSSOP-8 DT SUFFIX PLASTIC TSSOP PACKAGE CASE 948R-02 **ISSUE A**









- DIES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED

- FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE. 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE. 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY. 6. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INCHES			
DIM	MIN	MAX	MIN	MAX		
Α	2.90	3.10	0.114	0.122		
В	2.90	3.10	0.114	0.122		
С	0.80	1.10	0.031	0.043		
D	0.05	0.15	0.002	0.006		
F	0.40	0.70	0.016	0.028		
G	0.65	BSC	0.026	BSC		
К	0.25	0.40	0.010	0.016		
L	4.90	BSC	0.193	BSC		
М	0°	6 °	0°	6 °		

<u>Notes</u>

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